UNISONIC TECHNOLOGIES CO., LTD

MJE13007D

NPN SILICON TRANSISTOR

NPN BIPOLAR POWER TRANSISTOR FOR SWITCHING **POWER SUPPLY APPLICATIONS**

DESCRIPTION

The UTC MJE13007D is designed for high-voltage, high-speed power switching inductive circuits where fall time is critical. It is particularly suited for 115 and 220V switch mode applications.

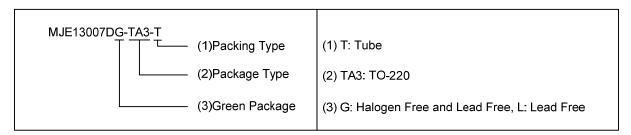
TO-220

FEATURES

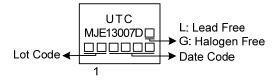
- * V_{CEO(SUS)} 400V
- * 700V Blocking Capability

ORDERING INFORMATION

Ordering Number		Deekees	Pin Assignment			Doolsing	
Lead Free	Halogen Free	Package	1	2	3	Packing	
MJE13007DL-TA3-T	MJE13007DG-TA3-T	TO-220	В	С	Е	Tube	



MARKING



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■ ABSOLUTE MAXIMUM RATING (T_A=25°C, unless otherwise specified)

PARAMETER		SYMBOL	RATINGS	UNIT
Collector-Emitter Sustaining Voltage		V_{CEO}	400	V
Collector-Emitter Breakdown Voltage		V_{CBO}	700	V
Emitter-Base Voltage		V_{EBO}	9.0	V
Collector Current	Continuous	I _C	8.0	Α
	Peak (1)	I _{CM}	16	Α
Base Current	Continuous	I _B	4.0	Α
	Peak (1)	I _{BM}	8.0	Α
Emitter Current	Continuous	Ι _Ε	12	Α
	Peak (1)	I _{EM}	24	Α
Power Dissipation	T _C = 25°C	P _D	80	W
Junction Temperature		TJ	+150	°C
Storage Temperature		T _{STG}	-55 ~ +150	°C

Note: Absolute maximum ratings are those values beyond which the device could be permanently damaged. Absolute maximum ratings are stress ratings only and functional device operation is not implied.

■ THERMAL DATA

PARAMETER	SYMBOL	RATINGS	UNIT	
Junction to Ambient	θ_{JA}	62.5	°C/W	
Junction to Case	θ_{JC}	1.56	°C/W	

Notes: 1. Pulse Test: Pulse Width = 5.0 ms, Duty Cycle ≤10%.

2. Measurement made with thermocouple contacting the bottom insulated mounting surface of the package (in a location beneath the die), the device mounted on a heatsink with thermal grease applied at a mounting torque of 6 to 8•lbs.

■ ELECTRICAL CHARACTERISTICS (T_C=25°C, unless otherwise specified)

PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT
Collector-Emitter Sustaining Voltage	V _{CEO(SUS)}	I _C =10mA, I _B =0	400			V
Collector Cutoff Current	I _{CBO}	V _{CES} =700V			0.1	mA
Collector Cuton Current		V _{CES} =700V, T _C =125°C			1.0	mA
Emitter Cutoff Current	I _{EBO}	V _{EB} =9.0V, I _C =0			100	μΑ
DC Current Gain	h _{FE1}	I _C =2.0A, V _{CE} =5.0V	8.0		40	
	h _{FE2}	I _C =5.0A, V _{CE} =5.0V	5.0		30	
	V _{CE(SAT)}	I _C =2.0A, I _B =0.4A			1.0	V
Callegtor Emitter Saturation Valtage		I _C =5.0A, I _B =1.0A			2.0	V
Collector-Emitter Saturation Voltage		I _C =8.0A, I _B =2.0A			4.0	V
		I _C =5.0A, I _B =1.0A, T _C =100°C			3.0	V
		I _C =2.0A, I _B =0.4A			1.2	V
Base-Emitter Saturation Voltage	$V_{BE(SAT)}$	I _C =5.0A, I _B =1.0A			1.6	V
		I _C =5.0A, I _B =1.0A, T _C =100°C			1.5	V
Current-Gain-Bandwidth Product	f _T	I _C =500mA, V _{CE} =10V, f=1.0 MHz	4.0	14		MHz
Output Capacitance	СОВ	V_{CB} =10V, I_E =0, f=0.1MHz		80		pF
RESISTIVE LOAD (TABLE 1)						
Storage Time	t _s	I _C =0.5A, I _B =10mA, Duty Cycle≤1.0%		3.4		μs

Note: Pulse Test: Pulse Width ≤ 300µs, Duty Cycle ≤ 2.0%.

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